



राष्ट्रीय प्रौद्योगिकी संस्थान सिलचर National Institute of Technology Silchar

(राष्ट्रीय महत्व का संस्थान)

(An Institute of National Importance)

www.nits.ac.in, Phone: 03842-242914, Fax: 03842-224797, Assam-788010 (INDIA)

Advertisement No.: NITS/Dean(R&C)/Physics./502/3/2019

Date: 27th July, 2019

Applications are invited from Indian citizens for a temporary of post of Junior Research Fellow for the DST-SERB sponsored project in the Department of Physics NIT Silchar.

Title of the project	Fabrication and Testing of Tandem Layered Quantum Dot Sensitized Solar Cell with Elevated Absorption
Sponsored Agency	DST-SERB
Project sanction number	ECR/2016/001186
No. of posts	01
Duration	06 months or till the completion of project
Principal Investigator (P.I)	Dr. Ranjith G. Nair

General Information and Terms & Conditions

1.	Age Limit	28 years
2.	Essential Qualification	M.Sc (Physics)
3.	Desirable Experience	Minimum 01 year of research experience in new generation solar cell fabrication and testing.
4.	Salary	Rs.14000 per month for non GATE For GATE candidates as per DST project norms Note: Candidate will be eligible for H.R.A as per the Project / Institute norms.
5.	Relaxation on qualification and age	SC/ST/OBC/WOMEN/PWD candidates will get relaxation as per Govt of India Rules.
6.	Last date of receiving/submission of filled up application form	6th August 2019
7.	Reporting	Applicants are requested to submit signed scanned copy of their filled-up applications along with C.V and other relevant documents. to Dr. Ranjith G. Nair, Assistant Professor, Physics Dept., NIT Silchar through his email- rgnair2007@gmail.com (Mob: +91-9401519326). Note: Hard copy of the filled application along with other relevant documents should be submitted at the time of interview.
8.	Date of interview, time, and venue	09th August 2019. Time and venue will be informed to the shortlisted candidates through email
9.	No objection certificate	Employed candidates are to submit no objection certificate from his / her employer at the time of interview.
10.	Institute right	The Institute has the discretion to restrict the number of candidates to be called for the interview on the basis of screening. No candidate may be recruited if suitable candidates are not found.
11.	Signing of the agreement	Selected candidates shall have to sign an agreement at the time of joining.

Sd/-

Associate Dean (R&C)
NIT Silchar.

National Institute of Technology Silchar

FORMAT of APPLICATION

for **Junior Research Fellow**

Paste recent
passport size
colored
photograph

1. Advertisement no. dated:
2. Title of the Project-
.....
3. Department:
4. Name of the applicant (in block letters):
5. Father's/Husband's Name:
6. Date of Birth (DD-MM-YYYY):
7. Age as on 06-08-2019 :
8. Postal Address:

E-mail: Phone no.:

9. Permanent Address:
10. Nationality:
11. Marital Status:
12. Whether belongs to SC/ST/PH/OBC: (If yes, attach certificate):
13. Educational Qualification: (Starting from Class X)

Exam. passed	Board/ University	Division	% age of marks / CPI	Year of passing	Subjects

14. NET/GATE Examinations Passed:

I. NET

II. GATE

Subject	Qualifying date	Valid upto		Subject	Score	Valid upto

15. Details of employments:

Sl. No.	Name of the Organization	Name of the post	Period	Scale of pay and present pay	Nature of duty

16. Any other relevant information that you may like to furnish:

Declaration

I declare that the above information are true and correct to the best of my knowledge and belief.

Date:

Place

Signature of the applicant